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# **DDR Termination Regulator**

#### **General Description**

The RT2530Q is a 2A sink/source tracking termination regulator. It is specifically designed for low-cost and low-external component count systems. The RT2530Q possesses a high speed operating amplifier that provides fast load transient response and only requires  $20\mu$ F of ceramic output capacitance. The RT2530Q supports remote sensing functions and all features required to power the DDRII/DDRIII VTT bus termination according to the JEDEC specification. In addition, the RT2530Q includes integrated sleep-state controls placing VTT in High-Z in S3 (suspend to RAM) The RT2530Q is available in the thermal efficient package SOP-8 (Exposed Pad).

## **Ordering Information**

RT2530Q

Package Type SP : SOP-8 (Exposed Pad-Option 1) Lead Plating System G : Green (Halogen Free and Pb Free)

Note :

Richtek products are :

- RoHS compliant and compatible with the current requirements of IPC/JEDEC J-STD-020.
- Suitable for use in SnPb or Pb-free soldering processes.

## **Marking Information**

RT2530Q GSPYMDNN RT2530QGSP : Product Number YMDNN : Date Code

#### Features

- Supports DDRII and DDRIII, Low-Power Requirement
  - Source/Sink 2A for DDRII and DDRIII
- Input Voltage Range : 3.1V to 3.6V
- VLDOIN Voltage Range : 1.2V to 1.8V
- Requires Only 20µF Ceramic Output Capacitance
- Supports High-Z in S3
- Integrated Divider Tracks 1/2 VDDQSNS for Both VTT and VTTREF
- Remote Sensing (VTTSNS)
- ±20mV Accuracy for VTT
- 10mA Buffered Reference (Sourcing/Sinking) (VTTREF)
- Built-In Soft-Start
- Current Limit
- Thermal Shutdown
- RoHS Compliant and Halogen Free

#### **Applications**

- DDRII, DDRIII Memory Termination
- SSTL-2, SSTL-18, HSTL Termination

## **Pin Configurations**







# **Functional Pin Description**

Pin No.	Pin Name	Pin Function
1, 9 (Exposed Pad)	GND	Ground. The exposed pad must be soldered to a large PCB and connected to GND for maximum power dissipation.
2	S3	Active Low Suspend to RAM Mode Control Input. In S3 state, VTT is turned off and left High-Z, VTTREF is active.
3	VTTSNS	VTT Voltage Sense Input. Connect to plus terminal of the output capacitor.
4	VTTREF	Buffered Output. The reference output voltage equals to VDDQSNS / 2.
5	VDDQSNS	VLDOIN Sense Input.
6	VIN	Supply Voltage Input for Control Circuit.
7	VLDOIN	Power Input for VTT Output Stage.
8	VTT	Power Output of the Regulation. The output voltage equals to VDDQSNS / 2.

# **Function Block Diagram**



Table	1.	S3	Control	Table
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State	S3	VTT	VTTREF
Normal	High	0.75V	0.75V
Standby	Low	High-Z	0.75V

## Operation

#### Shutdown Mode

The shutdown mode will happen when the S3 input voltage is under the logic threshold. The VTT pin will be high impedance and VTTREF will remain active under shutdown mode.

#### VIN OK and Thermal Shutdown

The regulator will detect VIN voltage and junction temperature. When VIN is lower than the VIN OK threshold or the junction temperature is over the thermal shutdown threshold, both the VTT and VTTREF will be discharged to GND.

#### VTTREF Buffer

The buffer senses the input voltage from VDDQSNS and provides an internal reference voltage of VDDQSNS/2 for VTT regulator.

#### **VTT Regulator**

The VTT output is capable of sinking and sourcing current while sensing from the VTTSNS pin to regulate the output precisely to VTTREF.



# Absolute Maximum Ratings (Note 1)

Supply Input Voltage, VIN     Supply Input Voltage, VLDOIN, VDDQSNS	
<ul> <li>Power Dissipation, P<sub>D</sub> @ T<sub>A</sub> = 25°C</li> <li>SOP-8 (Exposed Pad)</li> </ul>	2.04W
Package Thermal Resistance (Note 2)	
SOP-8 (Exposed Pad), θ <sub>JA</sub> SOP-8 (Exposed Pad), θ <sub>JC</sub>	
Lead Temperature (Soldering, 10 sec.)	
Junction Temperature     Storage Temperature Range	
ESD Susceptibility (Note 3)     HBM (Human Body Model)	2kV

# Recommended Operating Conditions (Note 4)

Supply Input Voltage, VIN	3.1V to 3.6V
Supply Input Voltage, VLDOIN, VDDQSNS	1.2V to 1.8V
Junction Temperature Range	–40°C to 125°C
Ambient Temperature Range	–40°C to 85°C

### **Electrical Characteristics**

(V<sub>IN</sub> = 3.3V, VLDOIN = VDDQSNS = 1.5V,  $T_A = -40^{\circ}C$  to 85°C, unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
VIN Supply Current	Ivin	No Load, S3 = 3.3V			2	mA
VIN Standby Current	IVINSTB	No Load, S3 = 0V			300	μA
VLDOIN Supply Current	I <sub>VLDOIN</sub>	No Load, S3 = 3.3V			2	mA
VLDOIN Standby Current	IVLDOINSTB	No Load, S3 = 0V			10	μA
VDDQSNS Input Current	IVDDQSNS	S3 = 3.3V			50	μA
VTTSNS Input Current	IVTTSNS	S3 = 3.3V			1	μA
VTT Output Voltage	VTT			VTTREF		V
VTT Output Tolerance to	Vvtttol	VDDQSNS = VLDOIN = 1.5V,   I <sub>VTT</sub>   = 0A, I <sub>VTTREF</sub> = 0A	-20		20	~~\/
VTTREF		VDDQSNS = VLDOIN = 1.5V,   I <sub>VTT</sub>   = 1.5A, I <sub>VTTREF</sub> = 0A	-40		40	mV
VTT Source Current Limit	I <sub>VTTOCLsr</sub>	VTT = 0V	2.3	3.3		А
VTT Sink Current Limit	I <sub>VTTOCLsk</sub>	VTT = VDDQSNS	2.3	4.3		А
		VDDQSNS = 1.5V, IVTTREF = 0mA	0.735	0.75	0.765	v
VTTREF Output Voltage	Vvttref	VDDQSNS = 1.5V, IVTTREF < 10mA	0.735	0.75	0.765	V

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Parameter		Symbol	Test Conditions	Min	Тур	Max	Unit
UVLO Threshold Voltage			Rising			2.7	V
UVLO Intesh	old voltage	Vuvlo	Falling	1.4		2.4	V
S3 Input Logic-High		VIH		1.6			v
Voltage	Logic-Low	VIL				0.4	
S3 Input Leak	S3 Input Leakage Current					1	μA
Thermal Shutdown Protection		T <sub>SD</sub>			160		°C
Thermal Shutdown Hysteresis		$\Delta T_{SD}$			20		°C

**Note 1.** Stresses beyond those listed "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions may affect device reliability.

Note 2.  $\theta_{JA}$  is measured at  $T_A = 25^{\circ}C$  on a high effective thermal conductivity four-layer test board per JEDEC 51-7.  $\theta_{JC}$  is measured at the exposed pad of the package.

Note 3. Devices are ESD sensitive. Handling precaution is recommended.

Note 4. The device is not guaranteed to function outside its operating conditions.



# **Typical Application Circuit**



# **Typical Operating Characteristics**











S3 Threshold Voltage vs. Temperature



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# **RT2530Q**





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### **Application Information**

The RT2530Q is a 2A sink/source tracking termination regulator. It is specifically designed for low-cost and low-external component count system such as notebook PC applications. The RT2530Q possesses a high speed operating amplifier that provides fast load transient response and only requires a  $10\mu$ F ceramic input capacitor and two  $10\mu$ F ceramic output capacitors.

#### **VTTREF Regulator**

VTTREF is a reference output voltage with source/sink current capability up to 10mA. To ensure stable operation  $0.1\mu$ F ceramic capacitor between VTTREF and GND is recommended.

#### S3 Logic Control

The S3 terminal should be connected to SLP\_S3 signals respectively. Both VTTREF and VTT are turned on at normal state (S3 = High). In standby state (S3 = Low), VTTREF is kept alive while VTT is turned off and left high impedance.

Table 2. S3 0	Control Talbe
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STATE	S3	VTT	VTTREF
Normal	Н	ON	ON
Standby	L	OFF (High-Z)	ON

#### **Capacitor Selection**

Good bypassing is recommended from VLDOIN to GND to help improve AC performance. A  $10\mu$ F or greater input capacitor located as close as possible to the IC is recommended. The input capacitor must be located at a distance of less than 0.5 inches from the VLDOIN pin of the IC.

Adding a  $1\mu$ F ceramic capacitor close to the VIN pin and it should be kept away from any parasitic impedance from the supply power. For stable operation, the total capacitance of the ceramic capacitor at the VTT output terminal must not be larger than  $30\mu$ F. The RT2530Q is designed specifically to work with low ESR ceramic output capacitor in space saving and performance consideration. Larger output capacitance can reduce the noise and improve load transient response, stability and PSRR. The output capacitor should be located near the VTT output terminal pin as close as possible.

#### **Thermal Considerations**

For continuous operation, do not exceed absolute maximum junction temperature. The maximum power dissipation depends on the thermal resistance of the IC package, PCB layout, rate of surrounding airflow, and difference between junction and ambient temperature. The maximum power dissipation can be calculated by the following formula :

 $\mathsf{P}_{\mathsf{D}(\mathsf{MAX})} = (\mathsf{T}_{\mathsf{J}(\mathsf{MAX})} - \mathsf{T}_{\mathsf{A}}) / \theta_{\mathsf{JA}}$ 

where  $T_{J(MAX)}$  is the maximum junction temperature,  $T_A$  is the ambient temperature, and  $\theta_{JA}$  is the junction to ambient thermal resistance.

For recommended operating condition specifications, the maximum junction temperature is 125°C. The junction to ambient thermal resistance,  $\theta_{JA}$ , is layout dependent. For SOP-8 (Exposed Pad) package, the thermal resistance,  $\theta_{JA}$ , is 49°C/W on a standard JEDEC 51-7 four-layer thermal test board. The maximum power dissipation at  $T_A = 25^{\circ}$ C can be calculated by the following formula :

 $P_{D(MAX)} = (125^{\circ}C - 25^{\circ}C) / (49^{\circ}C/W) = 2.04W$  for SOP-8 (Exposed Pad) package

The maximum power dissipation depends on the operating ambient temperature for fixed  $T_{J(MAX)}$  and thermal resistance,  $\theta_{JA}$ . The derating curve in Figure 1 allows the designer to see the effect of rising ambient temperature on the maximum power dissipation.



Figure 1. Derating Curve of Maximum Power Dissipation

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# **Outline Dimension**



Symbol		Dimensions I	n Millimeters	<b>Dimensions In Inches</b>	
		Min	Max	Min	Max
А		4.801	5.004	0.189	0.197
В		3.810	4.000	0.150	0.157
С		1.346	1.753	0.053	0.069
D		0.330	0.510	0.013	0.020
F		1.194	1.346	0.047	0.053
Н		0.170	0.254	0.007	0.010
I		0.000	0.152	0.000	0.006
J		5.791	6.200	0.228	0.244
М		0.406	1.270	0.016	0.050
Option 1	Х	2.000	2.300	0.079	0.091
Option 1	Y	2.000	2.300	0.079	0.091
Option 2	Х	2.100	2.500	0.083	0.098
	Y	3.000	3.500	0.118	0.138

#### 8-Lead SOP (Exposed Pad) Plastic Package

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